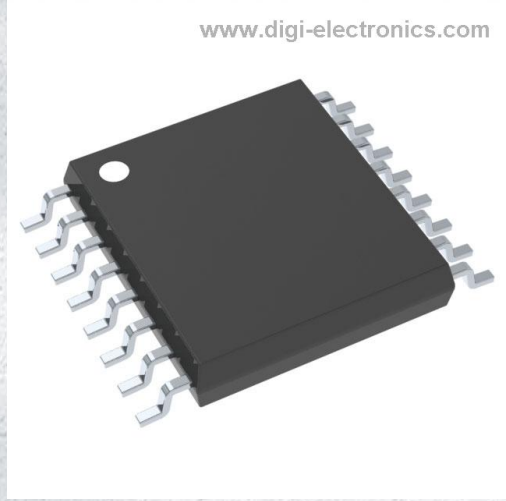
SN74LV4053APWR Datasheet



DiGi Electronics Part Number	SN74LV4053APWR-DG
Manufacturer	Texas Instruments
Manufacturer Product Number	SN74LV4053APWR
Description	IC SWITCH SPDT X 3 75OHM 16TSSOP
Detailed Description	3 Circuit IC Switch 2:1 75Ohm 16-TSSOP

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Manufacturer Product Number:	Manufacturer:
SN74LV4053APWR	Texas Instruments
Series:	Product Status:
-	Active
Switch Circuit:	Multiplexer/Demultiplexer Circuit:
SPDT	2:1
Number of Circuits:	On-State Resistance (Max):
3	75Ohm
Channel-to-Channel Matching (ΔRon):	Voltage - Supply, Single (V+):
1.3Ohm	2V ~ 5.5V
Voltage - Supply, Dual (V±):	Switch Time (Ton, Toff) (Max):
-	14ns, 14ns
-3db Bandwidth:	Charge Injection:
50MHz	-
Channel Capacitance (CS(off), CD(off)):	Current - Leakage (IS(off)) (Max):
0.5pF, 8.2pF	100nA
Crosstalk:	Operating Temperature:
-45dB @ 1MHz	-40°C ~ 85°C (TA)
Mounting Type:	Package / Case:
Surface Mount	16-TSSOP (0.173", 4.40mm Width)
Supplier Device Package:	Base Product Number:
16-TSSOP	74LV4053

Environmental & Export classification

RoHS Status:	Moisture Sensitivity Level (MSL):
ROHS3 Compliant	1 (Unlimited)
REACH Status:	ECCN:
REACH Unaffected	EAR99
HTSUS:	
8542.39.0001	

SNx4LV4053A Triple 2-Channel Analog Multiplexers or Demultiplexers

1 Features

- 1.65V to 5.5V V_{CC} operation
- Support mixed-mode voltage operation on all ports
- High on-off output-voltage ratio
- Low crosstalk between switches
- Individual switch controls
- Extremely low input current
- Latch-up performance exceeds 250mA per JESD 17
- ESD protection exceeds JESD 22
  - 2000V Human-Body Model (A114-A)
  - 1000V Charged-Device Model (C101)

2 Applications

- Telecommunications
- Infotainment
- Signal gating and isolation
- Home appliances
- Programmable logic circuits
- Modulation and demodulation

3 Description

These triple 2-channel CMOS analog multiplexers/demultiplexers are designed for 1.65V to 5.5V V_{CC} operation.

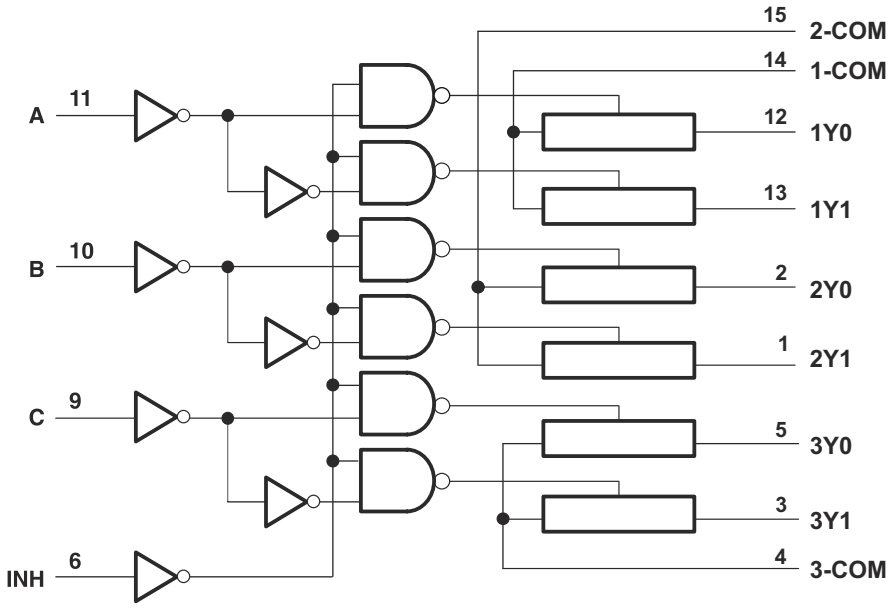
The SNx4LV4053A devices handle both analog and digital signals. Each channel permits signals with amplitudes up to 5.5V (peak) to be transmitted in either direction.

Applications include signal gating, chopping, modulation or demodulation (modem), and signal multiplexing for analog-to-digital and digital-to-analog conversion systems.

Package Information

PART NUMBER	PACKAGE(1)	PACKAGE SIZE(2)
SNx4LV4053A	D (SOIC, 16)	9.9mm × 6mm
	PW (TSSOP, 16)	5mm × 6.4mm
	RGY (VQFN, 16)	4mm × 3.5mm
	DYY (SOT-23-THIN, 16)	4.2mm x 3.26mm

(1) For more information, see Section 11.
(2) The package size (length × width) is a nominal value and includes pins, where applicable.



Functional Block Diagram

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4 Pin Configuration and Functions

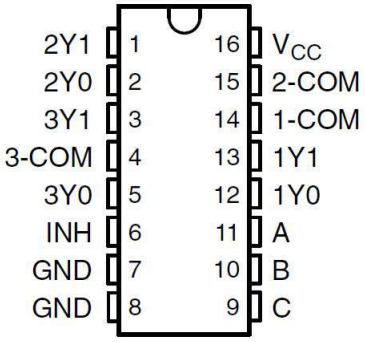


Figure 4-1. SN74LV4053A D, PW or DYY Packages, 16-Pin SOIC, TSSOP or SOT-23-THIN (Top View)

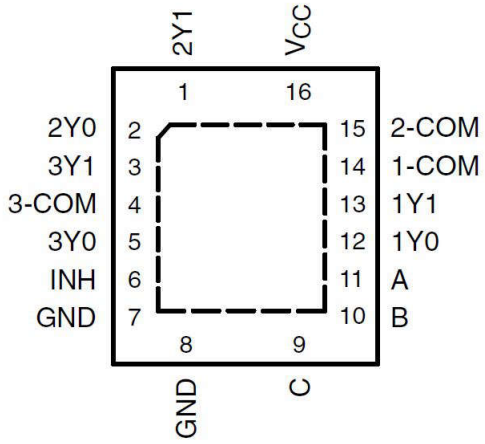


Figure 4-2. SN74LV4053A RGY, 16-Pin VQFN (Top View)

Table 4-1. Pin Functions

PIN		TYPE[2]	DESCRIPTION
NAME	NO.		
2Y1	1	I[1]	Input to mux 2
2Y0	2	I[1]	Input to mux 2
3Y1	3	I[1]	Input to mux 3
3-COM	4	O[1]	Output of mux 3
3Y0	5	I[1]	Input to mux 3
INH	6	I	Enables the outputs of the device. Logic low level with turn the outputs on, high level will turn them off.
GND	7	-	Ground
GND	8	-	Ground
C	9	I	Selector line for outputs (see Section 7.2 for specific information)
B	10	I	Selector line for outputs (see Section 7.2 for specific information)
A	11	I	Selector line for outputs (see Section 7.2 for specific information)
1Y0	12	I[1]	Input to mux 1
1Y1	13	I[1]	Input to mux 1
1-COM	14	O[1]	Output of mux 1
2-COM	15	O[1]	Output of mux 2
V_{CC}	16	I	Device power input

(1) These I/O descriptions represent the device when used as a multiplexer, when this device is operated as a demultiplexer pins 1Y0, 1Y1, 2Y0, 2Y1, 3Y0, 3Y1 may be considered outputs (O) and pins 1-COM, 2-COM, and 3-COM may be considered inputs (I).
(2) I = input, O = output

5 Specifications

5.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)(1) (3)

			MIN	MAX	UNIT
V_{CC}	Supply voltage		–0.5	7.0	V
V_I	Logic input voltage range		–0.5	7.0	V
V_{IO}	Switch I/O voltage range(2) (3)		–0.5	V_{CC} + 0.5	V
I_{IK}	Input clamp current	V_I < 0	–20		mA
I_{IOK}	Switch IO diode clamp current	V_{IO} < 0 or V_{IO} > V_{CC}	–50	50	mA
I_T	Switch continuous current	V_{IO} = 0 to V_{CC}		±25	mA
	Continuous current through V_{CC} or GND			±50	mA
T_J	Junction temperature			150	°C
T_{stg}	Storage temperature		–65	150	°C

(1) Operation outside the *Absolute Maximum Ratings* may cause permanent device damage. Absolute maximum ratings do not imply functional operation of the device at these or any other conditions beyond those listed under *Recommended Operating Conditions*. If briefly operating outside the *Recommended Operating Conditions* but within the *Absolute Maximum Ratings*, the device may not sustain damage, but it may not be fully functional. Operating the device in this manner may affect device reliability, functionality, performance, and shorten the device lifetime.
(2) Pins are diode-clamped to the power-supply rails. Over voltage signals must be voltage and current limited to maximum ratings.
(3) This value is limited to 5.5 V maximum

5.2 ESD Ratings

			VALUE	UNIT
$V_{(ESD)}$	Electrostatic discharge	Human body model (HBM), per ANSI/ESDA/JEDEC JS-001, all pins(1)	±2000	V
		Charged device model (CDM), per JEDEC specification JESD22-C101, all pins(2)	±1000	

(1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.
(2) JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.

5.3 Thermal Information: SN74LV4053A

THERMAL METRIC (1)		SN74LV4053A				UNIT
		D (SOIC)	PW (TSSOP)	RGY (VQFN)	DYY (SOT)	
		16 PINS	16 PINS	16 PINS	16 PINS	
$R_{\theta JA}$	Junction-to-ambient thermal resistance	115.2	140.2	89.4	199.7	°C/W
$R_{\theta JC(top)}$	Junction-to-case (top) thermal resistance	75.0	72.6	89.7	121.2	°C/W
$R_{\theta JB}$	Junction-to-board thermal resistance	76.6	98.7	65.4	129.0	°C/W
Ψ_{JT}	Junction-to-top characterization parameter	31.3	13.4	25.0	24.6	°C/W
Ψ_{JB}	Junction-to-board characterization parameter	75.7	97.3	65.2	126.7	°C/W
$R_{\theta JC(bot)}$	Junction-to-case (bottom) thermal resistance	N/A	N/A	48.9	N/A	°C/W

(1) For more information about traditional and new thermal metrics, see the Semiconductor and IC Package Thermal Metrics application report.

5.4 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)(1)

			MIN	NOM	MAX	UNIT
V_{CC}	Supply voltage		1(2)		5.5	V
V_{IH}	High-level input voltage, logic control inputs	V_{CC} = 1.65	1.2		5.5	V
		V_{CC} = 2 V	1.5		5.5	
		V_{CC} = 2.3 V to 2.7 V	V_{CC} x 0.7		5.5	
		V_{CC} = 3 V to 3.6 V	V_{CC} x 0.7		5.5	
		V_{CC} = 4.5 V to 5.5 V	V_{CC} x 0.7		5.5	
V_{IL}	Low-level input voltage, logic control inputs	V_{CC} = 1.65	0		0.4	V
		V_{CC} = 2 V	0		0.5	
		V_{CC} = 2.3 V to 2.7 V	0		V_{CC} x 0.3	
		V_{CC} = 3 V to 3.6 V	0		V_{CC} x 0.3	
		V_{CC} = 4.5 V to 5.5 V	0		V_{CC} x 0.3	
V_I	Logic control input voltage		0		5.5	V
V_{IO}	Switch input or output voltage		0		V_{CC}	V
Δt/ΔV	Logic input transition rise or fall rate	V_{CC} = 2.3 V to 2.7 V			200	ns/V
		V_{CC} = 3 V to 3.6 V			100	
		V_{CC} = 4.5 V to 5.5 V			20	
T_A	Ambient temperature		–40		125	°C

(1) All unused inputs of the device must be held at V_{CC} or GND to ensure proper device operation. Refer to TI application report *Implications of Slow or Floating CMOS Inputs*, SCBA004.
(2) When using a V_{CC} of ≤1.2 V, it is recommended to use these devices only for transmitting digital signals. When supply voltage is near 1.2 V the analog switch ON resistance becomes very non-linear

5.5 Electrical Characteristics

over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER		Condition	T_A	V_{CC}	MIN	TYP	MAX	UNIT
r_{ON}	ON-state switch resistance	I_T = 2 mA, V_I = V_{CC} or GND, V_{INH} = V_{IL}	25°C	1.65 V		60	150	Ω
r_{ON}	ON-state switch resistance	I_T = 2 mA, V_I = V_{CC} or GND, V_{INH} = V_{IL}	–40°C to 85°C	1.65 V			225	Ω
r_{ON}	ON-state switch resistance	I_T = 2 mA, V_I = V_{CC} or GND, V_{INH} = V_{IL}	–40°C to 125°C	1.65 V			225	Ω
r_{ON}	ON-state switch resistance	I_T = 2 mA, V_I = V_{CC} or GND, V_{INH} = V_{IL}	25°C	2.3 V		38	180	Ω
			–40°C to 85°C				225	
			–40°C to 125°C				225	
			25°C	3 V		30	150	Ω
			–40°C to 85°C				190	
			–40°C to 125°C				190	
			25°C	4.5 V		22	75	Ω
			–40°C to 85°C				100	
			–40°C to 125°C				100	
$r_{ON(p)}$	Peak ON-state resistance	I_T = 2 mA, V_I = GND to V_{CC}, V_{INH} = V_{IL}	25°C	1.65 V		220	600	Ω

5.5 Electrical Characteristics (continued)

over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER		Condition	T_A	V_{CC}	MIN	TYP	MAX	UNIT
$r_{ON(p)}$	Peak ON-state resistance	I_T = 2 mA, V_I = GND to V_{CC}, V_{INH} = V_{IL}	–40°C to 85°C	1.65 V			700	Ω
$r_{ON(p)}$	Peak ON-state resistance	I_T = 2 mA, V_I = GND to V_{CC}, V_{INH} = V_{IL}	–40°C to 125°C	1.65 V			700	Ω
$r_{ON(p)}$	Peak ON-state resistance	I_T = 2 mA, V_I = GND to V_{CC}, V_{INH} = V_{IL}	25°C	2.3 V		113	500	Ω
			–40°C to 85°C				600	
			–40°C to 125°C				600	
			25°C	3 V		54	180	Ω
			–40°C to 85°C				225	
			–40°C to 125°C				225	
			25°C	4.5 V		31	100	Ω
			–40°C to 85°C				125	
			–40°C to 125°C				125	
Δr_{ON}	Difference in ON-state resistance between switches	I_T = 2 mA, V_I = GND to V_{CC}, V_{INH} = V_{IL}	25°C	1.65 V		3	40	Ω
Δr_{ON}	Difference in ON-state resistance between switches	I_T = 2 mA, V_I = GND to V_{CC}, V_{INH} = V_{IL}	–40°C to 85°C	1.65 V			50	Ω
Δr_{ON}	Difference in ON-state resistance between switches	I_T = 2 mA, V_I = GND to V_{CC}, V_{INH} = V_{IL}	–40°C to 85°C	1.65 V			50	Ω
Δr_{ON}	Difference in ON-state resistance between switches	I_T = 2 mA, V_I = GND to V_{CC}, V_{INH} = V_{IL}	25°C	2.3 V		2.1	30	Ω
			–40°C to 85°C				40	
			–40°C to 125°C				40	
			25°C	3 V		1.4	20	Ω
			–40°C to 85°C				30	
			–40°C to 125°C				30	
			25°C	4.5 V		1.3	15	Ω
			–40°C to 85°C				20	
			–40°C to 125°C				20	
I_{IH} I_{IL}	Control input current	V_I = 5.5 V or GND	25°C	0 to 5.5 V			0.1	μA
			–40°C to 85°C				1	
			–40°C to 125°C				2	
$I_{S(off)}$	OFF-state switch leakage current	V_I = V_{CC} and V_O = GND, or V_I = GND and V_O = V_{CC}, V_{INH} = V_{IH}	25°C	5.5 V			0.1	μA
			–40°C to 85°C				1	
			–40°C to 125°C				2	
$I_{S(on)}$	ON-state switch leakage current	V_I = V_{CC} or GND, V_{INH} = V_{IL} (see Figure4)	25°C	5.5 V			0.1	μA
			–40°C to 85°C				1	
			–40°C to 125°C				2	
I_{CC}	Supply current	V_I = V_{CC} or GND V_{INH} = 0 V	25°C	5.5 V		0.01		μA
			–40°C to 85°C				20	
			–40°C to 125°C				40	
C_{IC}	Control input capacitance	f = 10 MHz	25°C	3.3 V		2		pF

5.5 Electrical Characteristics (continued)

over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER		Condition	T_A	V_{CC}	MIN	TYP	MAX	UNIT
C_{OS}	Switch terminal capacitance	f = 10 MHz	25°C	3.3 V		5		pF
C_{IS}	Common ternminal capacitance	f = 10 MHz	25°C	3.3 V		23		pF
$C_{OS(on)}$	Common ternminal ON-capacitance	f = 10 MHz	25°C	3.3 V		23		pF
C_F	Feedthrough capacitance	f = 10 MHz	25°C	3.3 V		0.5		pF
C_{PD}	Power dissipation capacitance	C_L = 50 pF, f = 10 MHz	25°C	3.3 V		6		pF

5.6 Timing Characteristics V_{CC} = 2.5 V ± 0.2 V

PARAMETER		FROM (INPUT)	TO (OUTPUT)	CONDITIONS	T_A	MIN	TYP	MAX	UNIT
t_{PLH} t_{PHL}	Propagation delay time	COM or Yn	Yn or COM	C_L = 15 pF	25°C		1.9	10	ns
					–40°C to 85°C			16	
					–40°C to 125°C			18	
t_{PZH} t_{PZL}	Enable delay time	INH	COM or Yn	C_L = 15 pF	25°C		6.6	18	ns
					–40°C to 85°C			23	
					–40°C to 125°C			25	
t_{PHZ} t_{PLZ}	Disable delay time	INH	COM or Yn	C_L = 15 pF	25°C		7.4	18	ns
					–40°C to 85°C			23	
					–40°C to 125°C			25	
t_{PLH} t_{PHL}	Propagation delay time	COM or Yn	Yn or COM	C_L = 50 pF	25°C		3.8	12	ns
					–40°C to 85°C			18	
					–40°C to 125°C			20	
t_{PZH} t_{PZL}	Enable delay time	INH	COM or Yn	C_L = 50 pF	25°C		7.8	28	ns
					–40°C to 85°C			35	
					–40°C to 125°C			35	
t_{PHZ} t_{PLZ}	Disable delay time	INH	COM or Yn	C_L = 50 pF	25°C		11.5	28	ns
					–40°C to 85°C			35	
					–40°C to 125°C			35	

5.7 Timing Characteristics V_{CC} = 3.3 V ± 0.3 V

PARAMETER		FROM (INPUT)	TO (OUTPUT)	CONDITIONS	T_A	MIN	TYP	MAX	UNIT
t_{PLH} t_{PHL}	Propagation delay time	COM or Yn	Yn or COM	C_L = 15 pF	25°C		1.2	6	ns
					–40°C to 85°C			10	
					–40°C to 125°C			12	
t_{PZH} t_{PZL}	Enable delay time	INH	COM or Yn	C_L = 15 pF	25°C		4.7	12	ns
					–40°C to 85°C			15	
					–40°C to 125°C			18	
t_{PHZ} t_{PLZ}	Disable delay time	INH	COM or Yn	C_L = 15 pF	25°C		5.7	12	ns
					–40°C to 85°C			15	
					–40°C to 125°C			18	

5.7 Timing Characteristics V_{CC} = 3.3 V ± 0.3 V (continued)

PARAMETER		FROM (INPUT)	TO (OUTPUT)	CONDITIONS	T_A	MIN	TYP	MAX	UNIT
t_{PLH} t_{PHL}	Propagation delay time	COM or Yn	Yn or COM	C_L = 50 pF	25°C		2.5	9	ns
					–40°C to 85°C			12	
					–40°C to 125°C			14	
t_{PZH} t_{PZL}	Enable delay time	INH	COM or Yn	C_L = 50 pF	25°C		5.5	20	ns
					–40°C to 85°C			25	
					–40°C to 125°C			25	
t_{PHZ} t_{PLZ}	Disable delay time	INH	COM or Yn	C_L = 50 pF	25°C		8.8	20	ns
					–40°C to 85°C			25	
					–40°C to 125°C			25	

5.8 Timing Characteristics V_{CC} = 5 V ± 0.5 V

PARAMETER		FROM (INPUT)	TO (OUTPUT)	CONDITIONS	T_A	MIN	TYP	MAX	UNIT
t_{PLH} t_{PHL}	Propagation delay time	COM or Yn	Yn or COM	C_L = 15 pF	25°C		0.6	4	ns
					–40°C to 85°C			7	
					–40°C to 125°C			10	
t_{PZH} t_{PZL}	Enable delay time	INH	COM or Yn	C_L = 15 pF	25°C		3.5	8	ns
					–40°C to 85°C			10	
					–40°C to 125°C			12	
t_{PHZ} t_{PLZ}	Disable delay time	INH	COM or Yn	C_L = 15 pF	25°C		4.4	10	ns
					–40°C to 85°C			11	
					–40°C to 125°C			12	
t_{PLH} t_{PHL}	Propagation delay time	COM or Yn	Yn or COM	C_L = 50 pF	25°C		1.5	6	ns
					–40°C to 85°C			8	
					–40°C to 125°C			10	
t_{PZH} t_{PZL}	Enable delay time	INH	COM or Yn	C_L = 50 pF	25°C		4	14	ns
					–40°C to 85°C			18	
					–40°C to 125°C			18	
t_{PHZ} t_{PLZ}	Disable delay time	INH	COM or Yn	C_L = 50 pF	25°C		6.2	14	ns
					–40°C to 85°C			18	
					–40°C to 125°C			18	

5.9 AC Characteristics

PARAMETER	FROM (INPUT)	TO (OUTPUT)	Device	CONDITIONS		MIN	TYP	MAX	UNIT
Frequency response (switch on)	COM or Yn	Yn or COM	SN74LV4053	C_L = 50 pF, R_L = 600 Ω, F_{in} = 1 MHz (sine wave), (see Figure 7)(1)	V_{CC} = 2.3 V		40		MHz
					V_{CC} = 3 V		45		
					V_{CC} = 4.5 V		60		
Charge Injection (control input to signal output)	INH	COM or Yn		C_L = 50 pF, R_L = 600 Ω, F_{in} = 1 MHz (sine wave) (see Figure 9)	V_{CC} = 2.3 V		20		mV
					V_{CC} = 3 V		35		
					V_{CC} = 4.5 V		60		

5.9 AC Characteristics (continued)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	Device	CONDITIONS		MIN	TYP	MAX	UNIT
Feedthrough attenuation (switch off)	COM or Yn	Yn or COM		C_L = 50 pF, R_L = 600 Ω, F_{in} = 1 MHz (sine wave) (see Figure 10) (2)	V_{CC} = 2.3 V		–45		dB
					V_{CC} = 3 V		–45		
					V_{CC} = 4.5 V		–45		
Crosstalk (between any switches)	COM or Yn	Yn or COM		C_L = 50 pF, R_L = 600 Ω, F_{in} = 1 MHz (sine wave) (see Figure 8)(2)	V_{CC} = 2.3 V		–45		dB
					V_{CC} = 3 V		–45		
					V_{CC} = 4.5 V		–45		
Sine-wave distortion	COM or Yn	Yn or COM		C_L = 50 pF, R_L = 10 kΩ, F_{in} = 1 kHz (sine wave) (see Figure 11)	V_I = 2 V_{p-p} V_{CC} = 2.3 V		0.1		%
					V_I = 2.5 V_{p-p} V_{CC} = 3 V		0.1		
					V_I = 4 V_{p-p} V_{CC} = 4.5 V		0.1		

6 Parameter Measurement Information

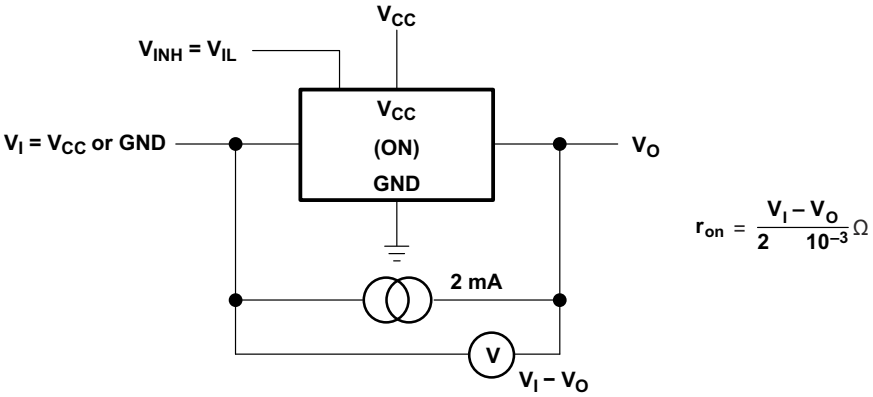


Figure 6-1. On-State Resistance Test Circuit

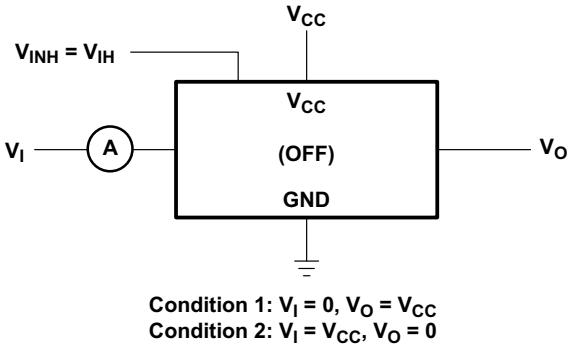


Figure 6-2. Off-State Switch Leakage-Current Test Circuit

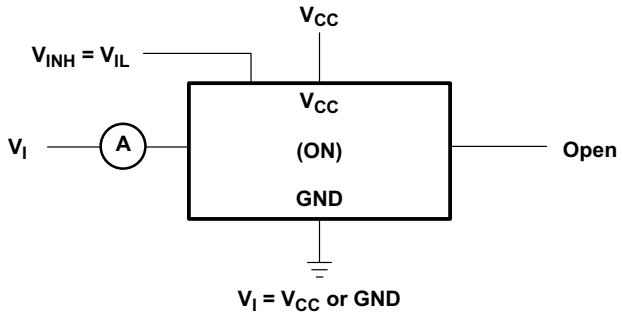


Figure 6-3. On-State Switch Leakage-Current Test Circuit

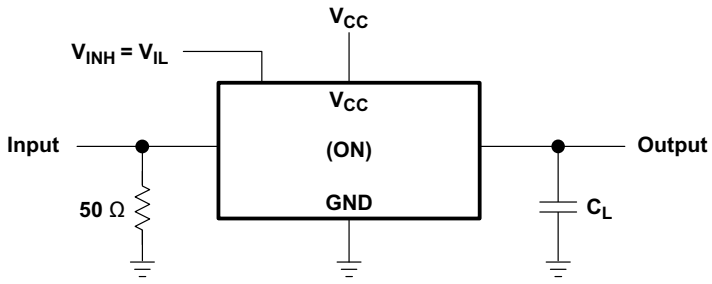
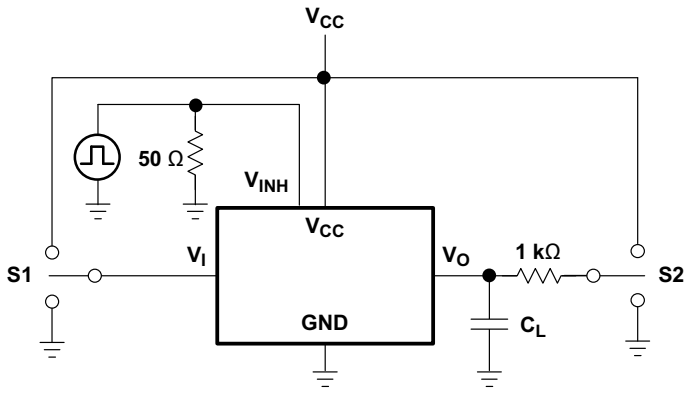
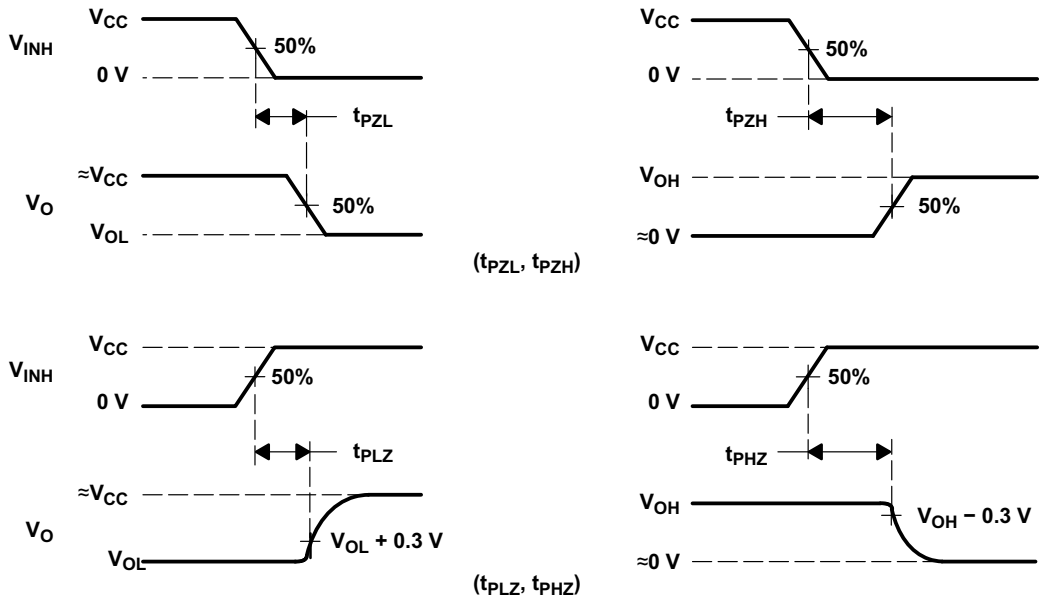


Figure 6-4. Propagation Delay Time, Signal Input to Signal Output



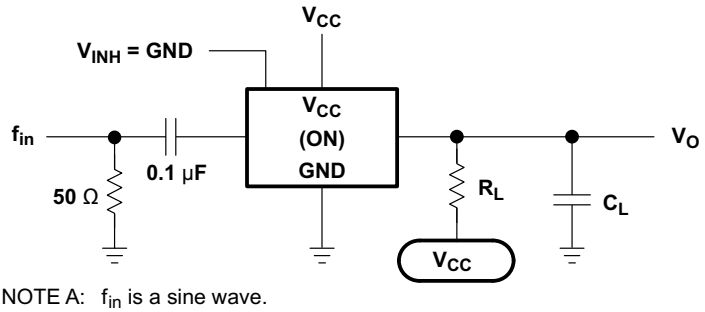
TEST	S1	S2
t_{PLZ}/t_{PZL} t_{PHZ}/t_{PZH}	GND V_{CC}	V_{CC} GND

TEST CIRCUIT



VOLTAGE WAVEFORMS

Figure 6-5. Switching Time (t_{PZL}, t_{PLZ}, t_{PZH}, t_{PHZ}), Control to Signal Output



NOTE A: f_{in} is a sine wave.

Figure 6-6. Frequency Response (Switch On)

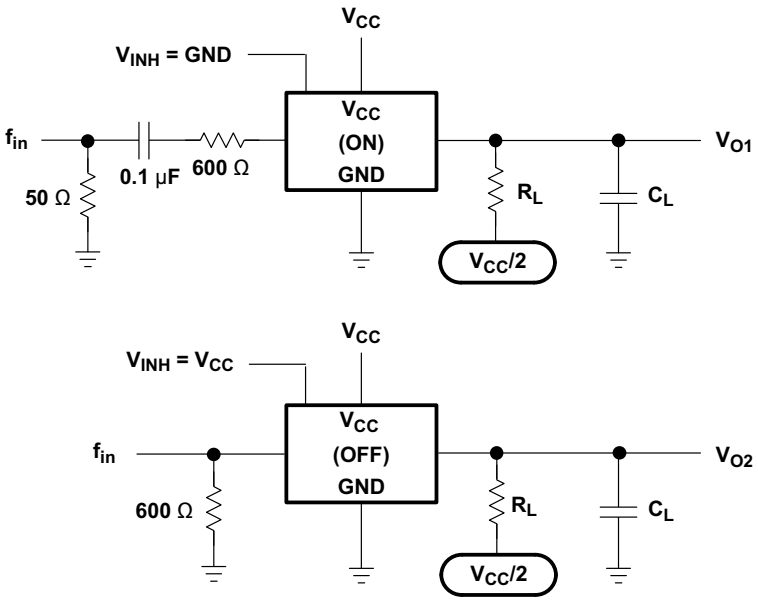


Figure 6-7. Crosstalk Between Any Two Switches

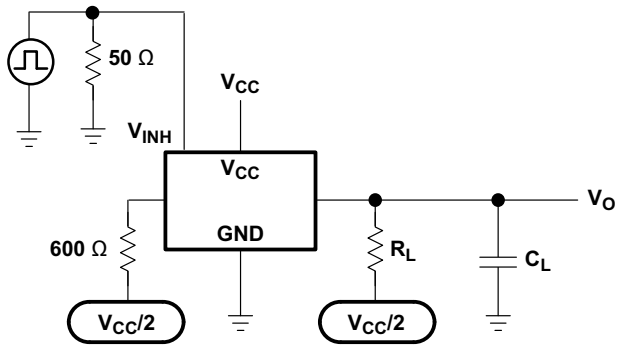


Figure 6-8. Crosstalk Between Control Input and Switch Output

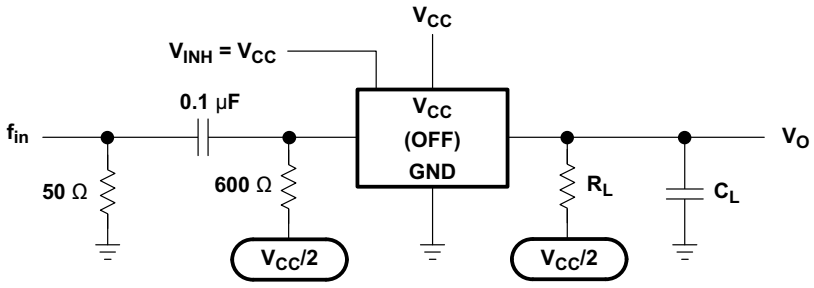


Figure 6-9. Feedthrough Attenuation (Switch Off)

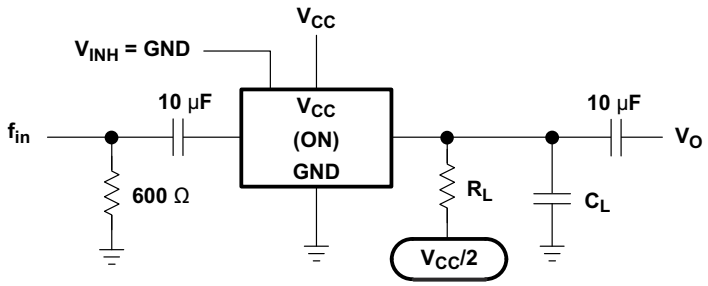
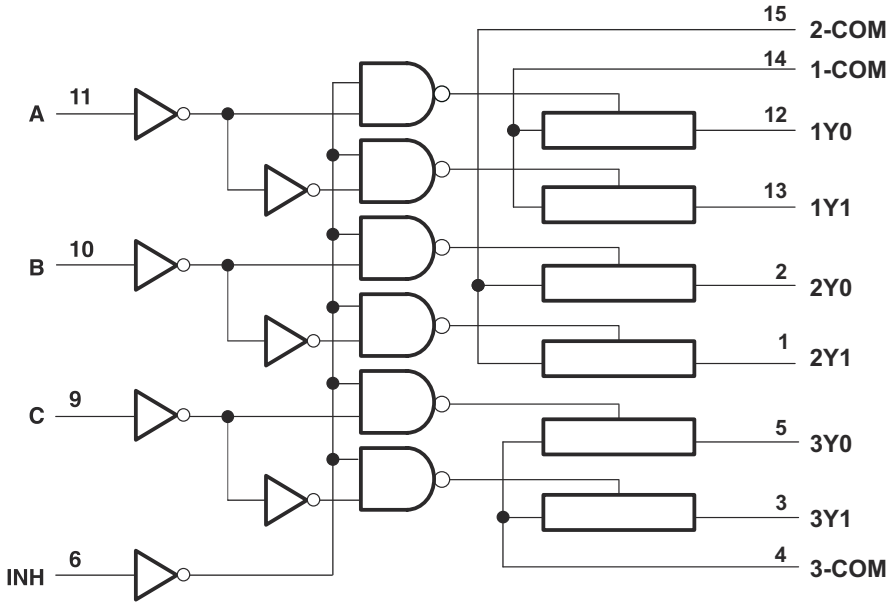


Figure 6-10. Sine-Wave Distortion

7 Detailed Description

7.1 Functional Block Diagram



7.2 Device Functional Modes

Function Table

INPUTS				ON CHANNEL
INH	C	B	A	
L	L	L	L	1Y0, 2Y0, 3Y0
L	L	L	H	1Y1, 2Y0, 3Y0
L	L	H	L	1Y0, 2Y1, 3Y0
L	L	H	H	1Y1, 2Y1, 3Y0
L	H	L	L	1Y0, 2Y0, 3Y1
L	H	L	H	1Y1, 2Y0, 3Y1
L	H	H	L	1Y0, 2Y1, 3Y1
L	H	H	H	1Y1, 2Y1, 3Y1
H	X	X	X	None

8 Application and Implementation

Note

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes, as well as validating and testing their design implementation to confirm system functionality.

8.1 Application Information

A multiplexer is used in applications where multiple signals share a resource. In the following example, several different sensors are connected to the analog-to-digital converter (ADC) of a microcontroller (MCU).

8.2 Typical Application

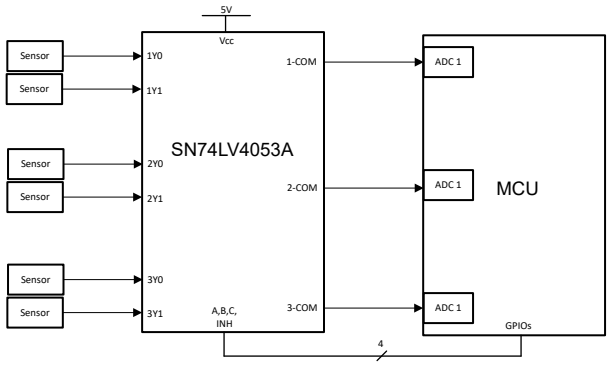


Figure 8-1. Typical Application Schematic

8.2.1 Design Requirements

Processing 8 different analog signals would normally require 8 separate ADCs, but the previous figure shows how to achieve this using only 2 ADCs and 3 GPIOs (general purpose input/outputs).

8.2.2 Detailed Design Procedure

To design with the SNx4LV4053A, a stable input voltage between 2V (see *Recommended Operating Conditions* for details) and 5.5V must be available. The characteristics of the signal that is being multiplexed so that no important information is lost due to timing or voltage level incompatibility with this device is another important design consideration.

8.3 Power Supply Recommendations

Most systems have a common 3.3V or 5V rail that may be used to supply the V_{CC} pin of this device. If this is not available, then a Switch-Mode-Power-Supply (SMPS) or a Linear Dropout Regulator (LDO) may be used to supply this device from a higher voltage rail.

8.4 Layout

8.4.1 Layout Guidelines

In general, it is best to keep signal lines as short and as straight as possible. Incorporation of microstrip or stripline techniques is also recommended when signal lines are greater than 1 inch in length. These traces must be designed with a characteristic impedance of either 50Ω or 75Ω, as required by the application. Be careful when placing this device too close to high voltage switching components, as they may cause interference.

8.4.2 Layout Example

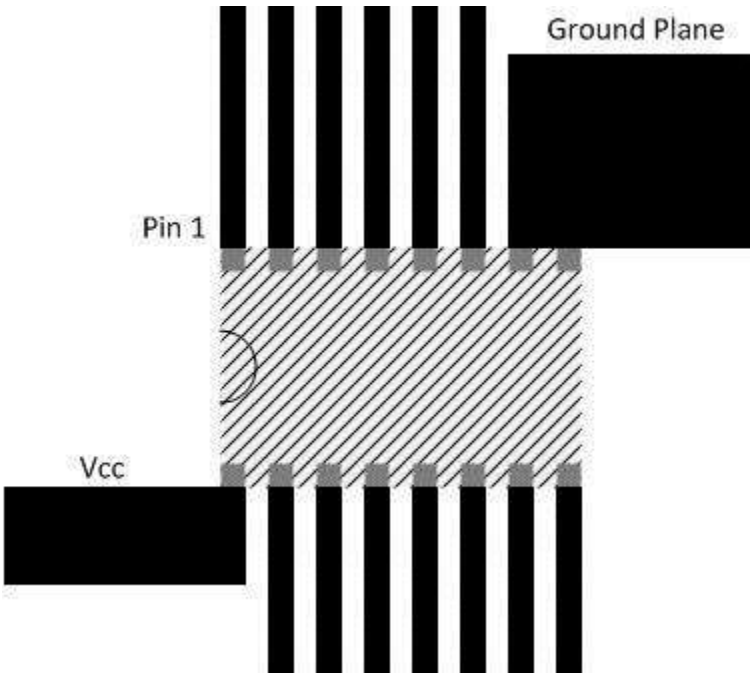


Figure 8-2. Layout Example Schematic

9 Device and Documentation Support

TI offers an extensive line of development tools. Tools and software to evaluate the performance of the device, generate code, and develop solutions are listed below.

9.1 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on ti.com. Click on *Notifications* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

9.2 Support Resources

TI E2E™ support forums are an engineer's go-to source for fast, verified answers and design help — straight from the experts. Search existing answers or ask your own question to get the quick design help you need.

Linked content is provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's Terms of Use.

9.3 Trademarks

TI E2E™ is a trademark of Texas Instruments.
All trademarks are the property of their respective owners.

9.4 Electrostatic Discharge Caution

This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

9.5 Glossary

TI Glossary	This glossary lists and explains terms, acronyms, and definitions.

10 Revision History

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

Changes from Revision L (June 2024) to Revision M (September 2024)	Page
• Added DYY package and size	1
• Added DYY package	3
• Added DYY package	4

Changes from Revision K (April 2005) to Revision L (June 2024)	Page
• Changed the numbering format for tables, figures, and cross-references throughout the document	1
• Added new VIH and VIL Specifications at 1.65V Vcc	5
• Increased max ambient temperature max to 125C	5
• Added Ron, Ron Peak, and Delta Ron Specifications at 1.65V Vcc	5
• Added Ron, Ron Peak, and Delta Ron Specifications at 125C	5
• Added Timing Specifications at 125C	7

11 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

TEXAS INSTRUMENTS

PACKAGE OPTION ADDENDUM

PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead finish/ Ball material (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
SN74LV4053AD	OBSOLETE	SOIC	D	16		TBD	Call TI	Call TI	-40 to 85	LV4053A	
SN74LV4053ADBR	NRND	SSOP	DB	16	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	LW053A	
SN74LV4053ADGVR	NRND	TVSOP	DGV	16	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	LW053A	
SN74LV4053ADR	ACTIVE	SOIC	D	16	2500	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	LV4053A	Samples
SN74LV4053ADYYR	ACTIVE	SOT-23-THIN	DYY	16	3000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	LV4053	Samples
SN74LV4053AN	NRND	PDIP	N	16	25	RoHS & Green	NIPDAU	N / A for Pkg Type	-40 to 85	SN74LV4053AN	
SN74LV4053ANSR	NRND	SOP	NS	16	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	74LV4053A	
SN74LV4053APW	OBSOLETE	TSSOP	PW	16		TBD	Call TI	Call TI	-40 to 85	LW053A	
SN74LV4053APWR	ACTIVE	TSSOP	PW	16	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	LW053A	Samples
SN74LV4053APWRG4	OBSOLETE	TSSOP	PW	16		TBD	Call TI	Call TI	-40 to 85	LW053A	
SN74LV4053APWT	OBSOLETE	TSSOP	PW	16		TBD	Call TI	Call TI	-40 to 85	LW053A	
SN74LV4053ARGYR	ACTIVE	VQFN	RGY	16	3000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	LW053A	Samples

(1) The marketing status values are defined as follows:
ACTIVE: Product device recommended for new designs.
LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.
NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.
PREVIEW: Device has been announced but is not in production. Samples may or may not be available.
OBSOLETE: TI has discontinued the production of the device.

(2) **RoHS:** TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".
RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.
Green: TI defines "Green" to mean the content of Chlorine (Cl) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

(3) MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

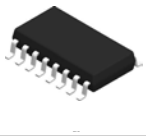
(6) Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

OTHER QUALIFIED VERSIONS OF SN74LV4053A :

- Automotive : SN74LV4053A-Q1
- Enhanced Product : SN74LV4053A-EP

NOTE: Qualified Version Definitions:

- Automotive - Q100 devices qualified for high-reliability automotive applications targeting zero defects
- Enhanced Product - Supports Defense, Aerospace and Medical Applications

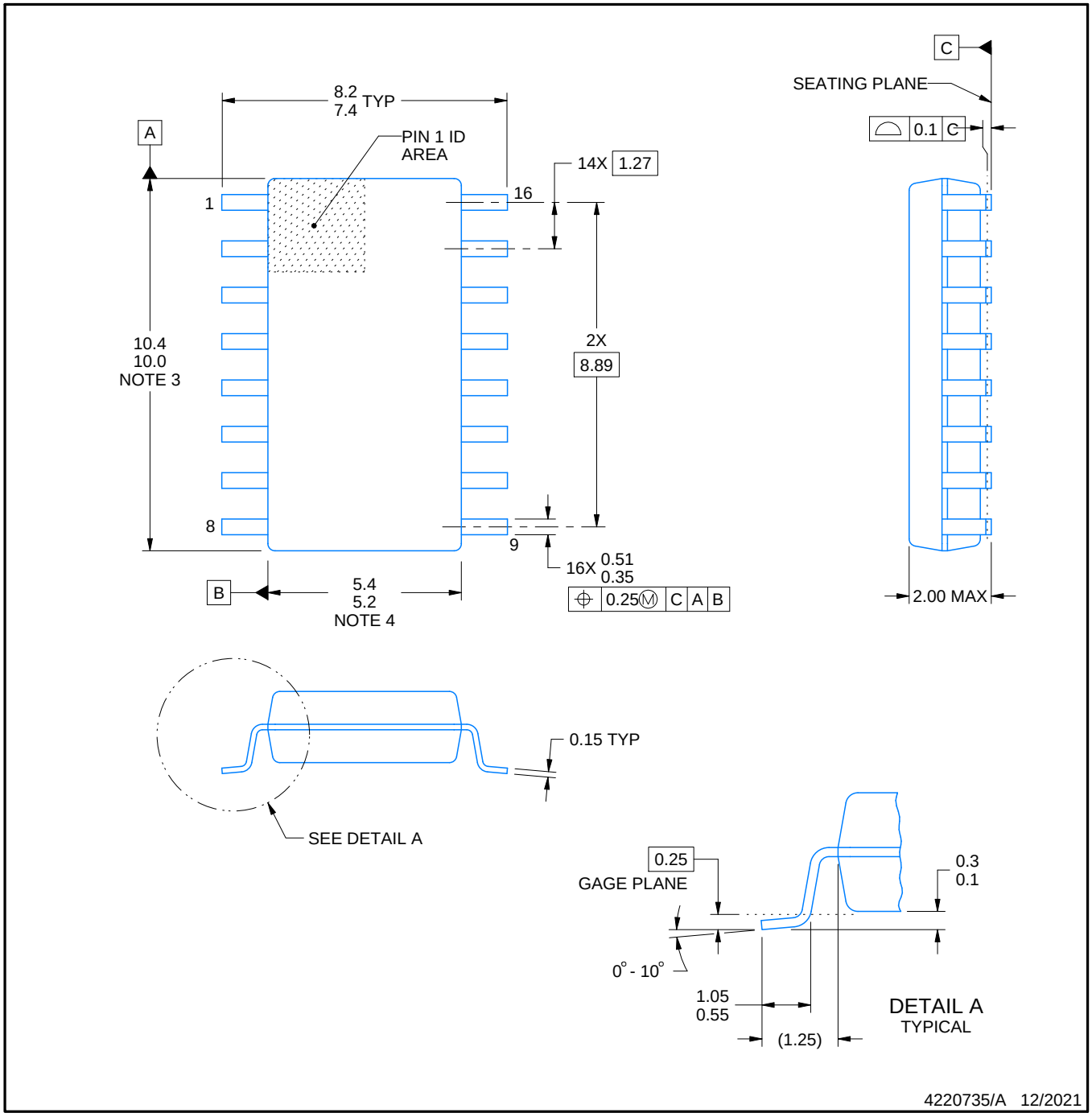


PACKAGE OUTLINE

NS0016A

SOP - 2.00 mm max height

SOP



NOTES:

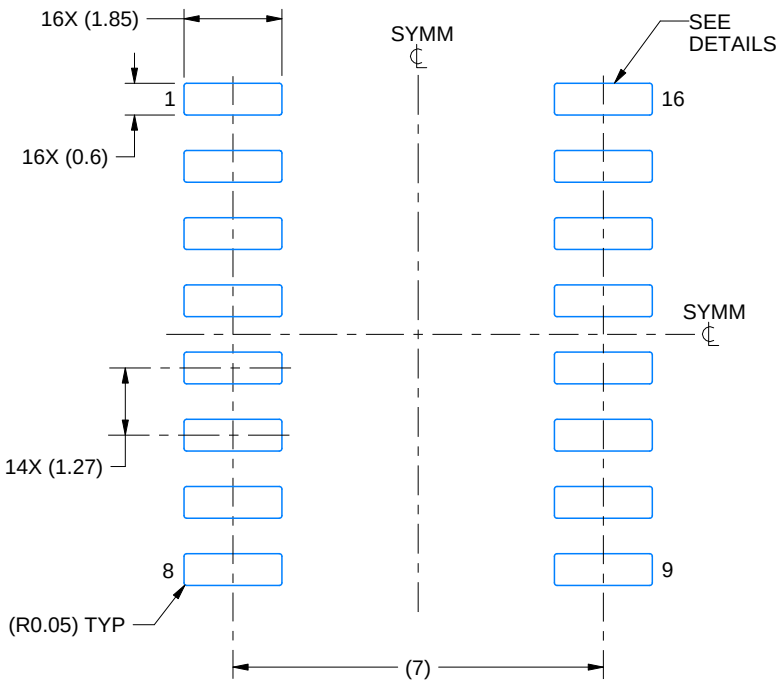
1. All linear dimensions are in millimeters. Dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm, per side.
4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm, per side.

EXAMPLE BOARD LAYOUT

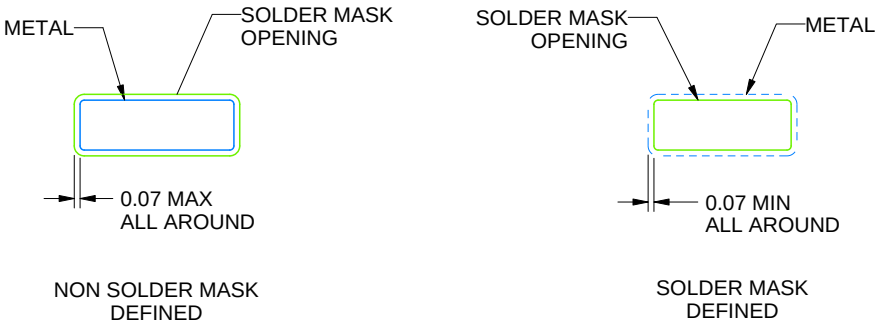
NS0016A

SOP - 2.00 mm max height

SOP



LAND PATTERN EXAMPLE
SCALE:7X



SOLDER MASK DETAILS

4220735/A 12/2021

NOTES: (continued)

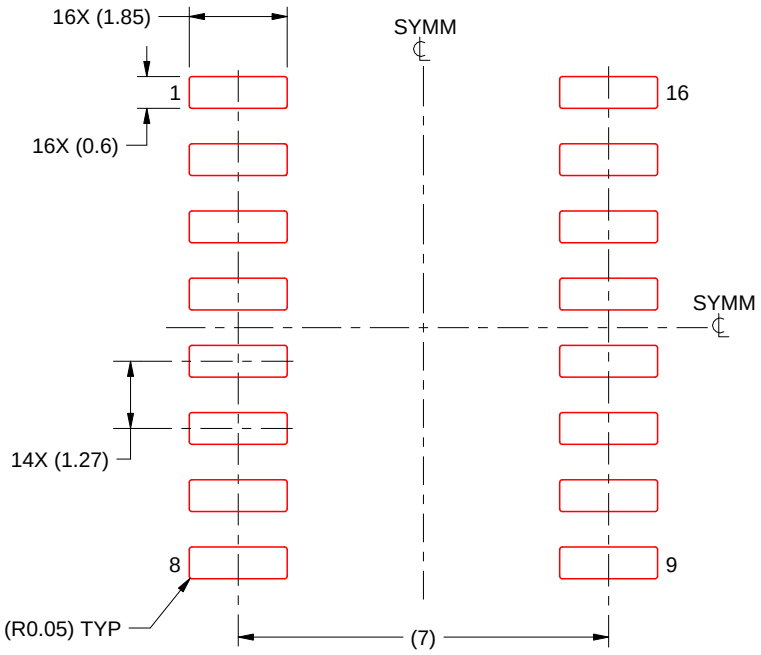
5. Publication IPC-7351 may have alternate designs.
6. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

EXAMPLE STENCIL DESIGN

NS0016A

SOP - 2.00 mm max height

SOP



SOLDER PASTE EXAMPLE
BASED ON 0.125 mm THICK STENCIL
SCALE:7X

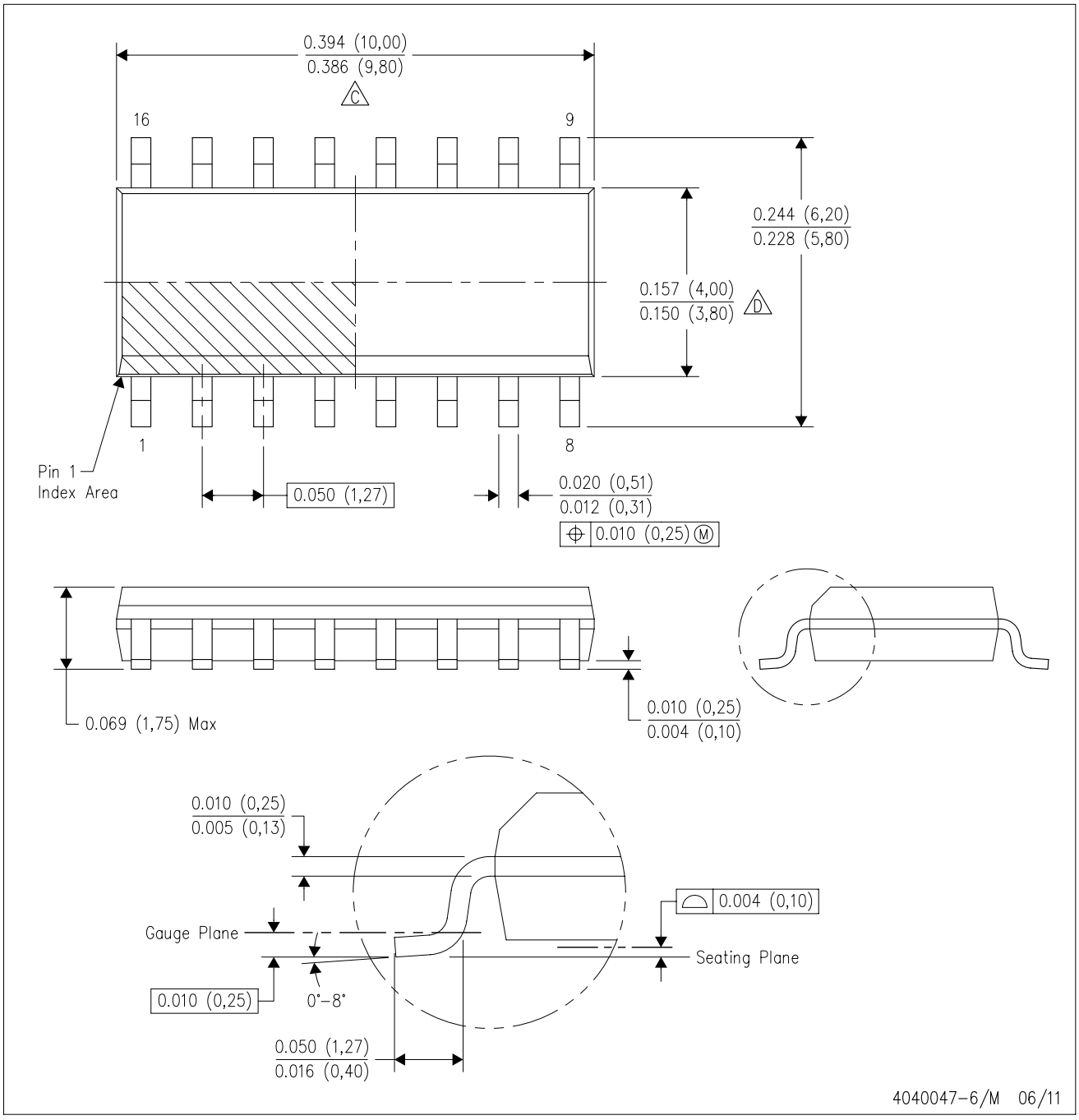
4220735/A 12/2021

NOTES: (continued)

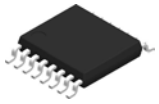
7. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
8. Board assembly site may have different recommendations for stencil design.

MECHANICAL DATA

D (R–PDSO–G16) PLASTIC SMALL OUTLINE



NOTES:
A. All linear dimensions are in inches (millimeters).
B. This drawing is subject to change without notice.
C. Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
D. Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
E. Reference JEDEC MS–012 variation AC.

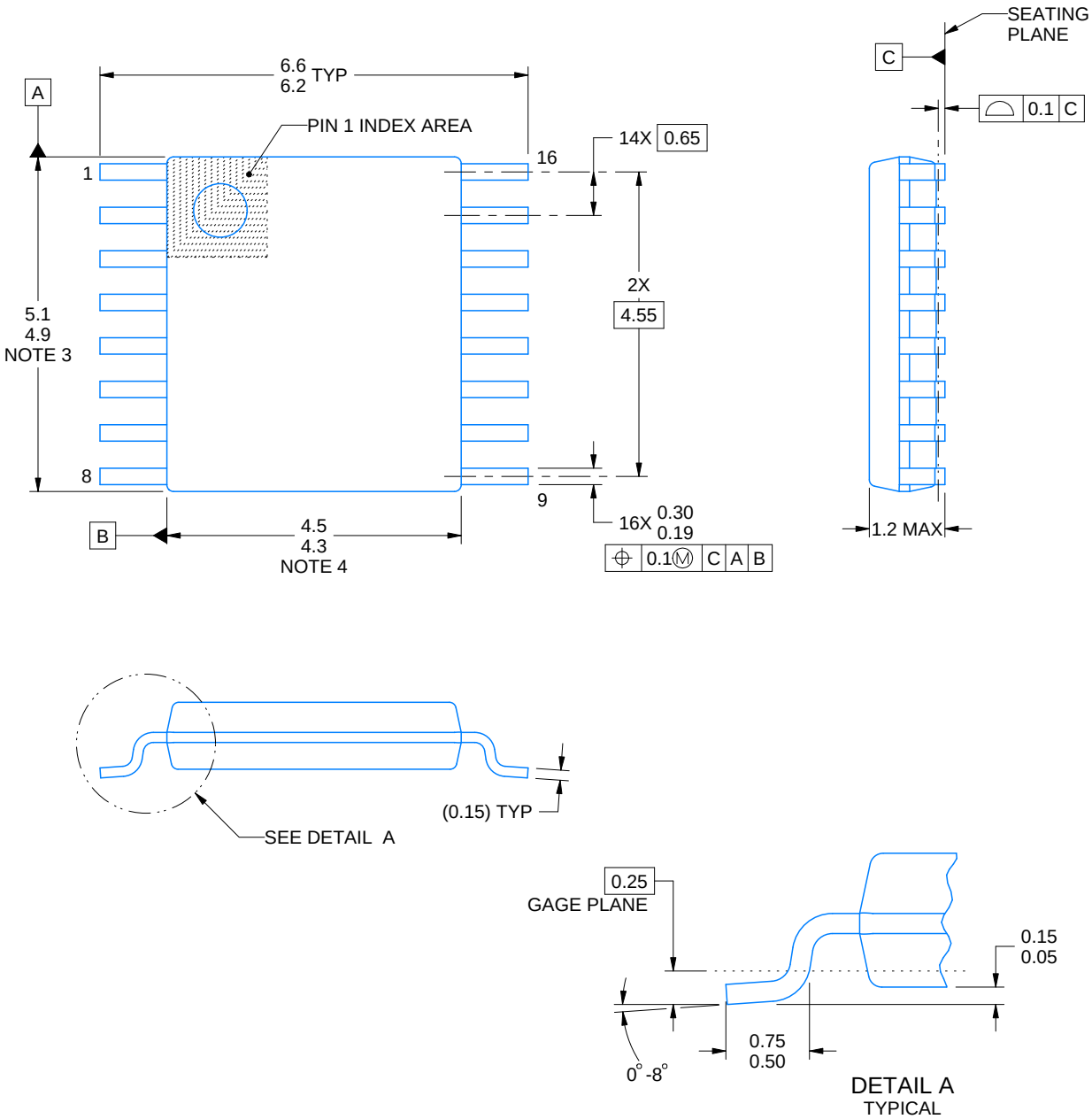


PACKAGE OUTLINE

PW0016A

TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



NOTES:

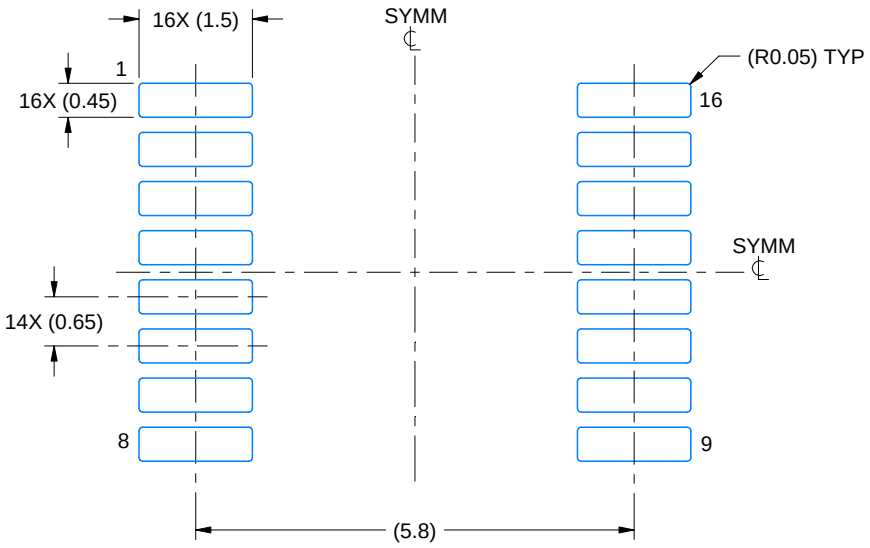
1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm per side.
4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
5. Reference JEDEC registration MO-153.

EXAMPLE BOARD LAYOUT

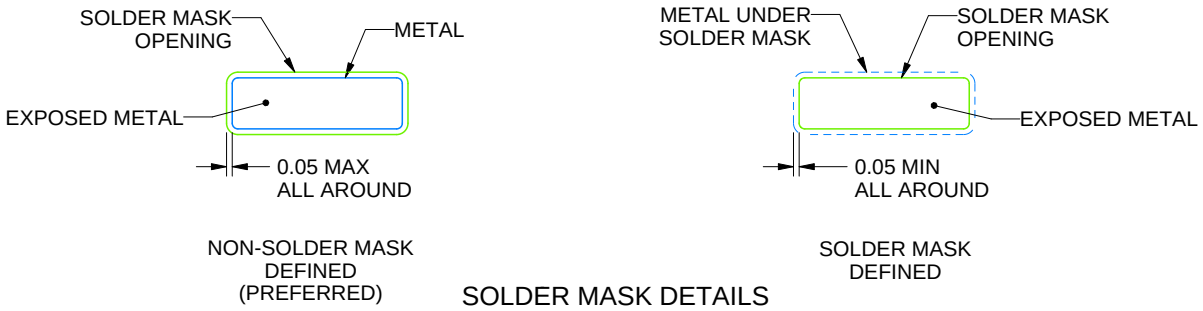
PW0016A

TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE: 10X



SOLDER MASK DETAILS

4220204/A 02/2017

NOTES: (continued)

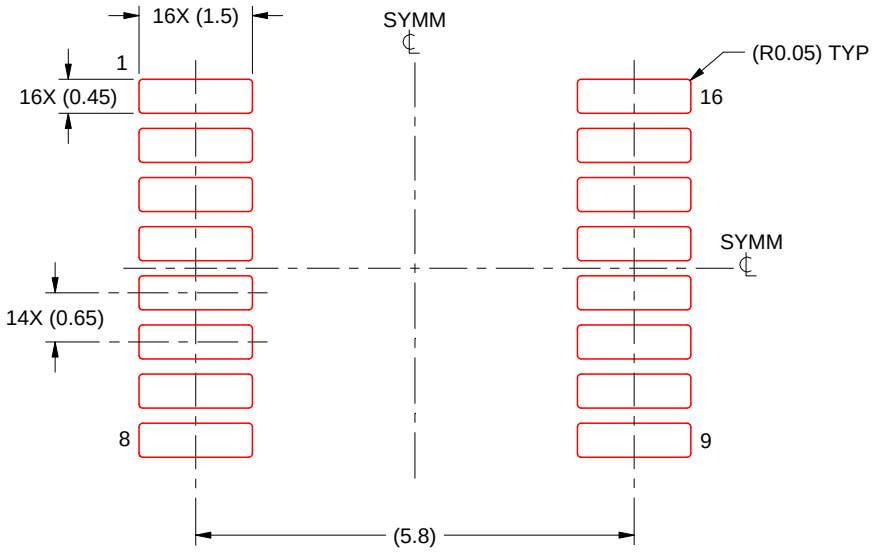
6. Publication IPC-7351 may have alternate designs.
7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

EXAMPLE STENCIL DESIGN

PW0016A

TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



SOLDER PASTE EXAMPLE
BASED ON 0.125 mm THICK STENCIL
SCALE: 10X

4220204/A 02/2017

NOTES: (continued)

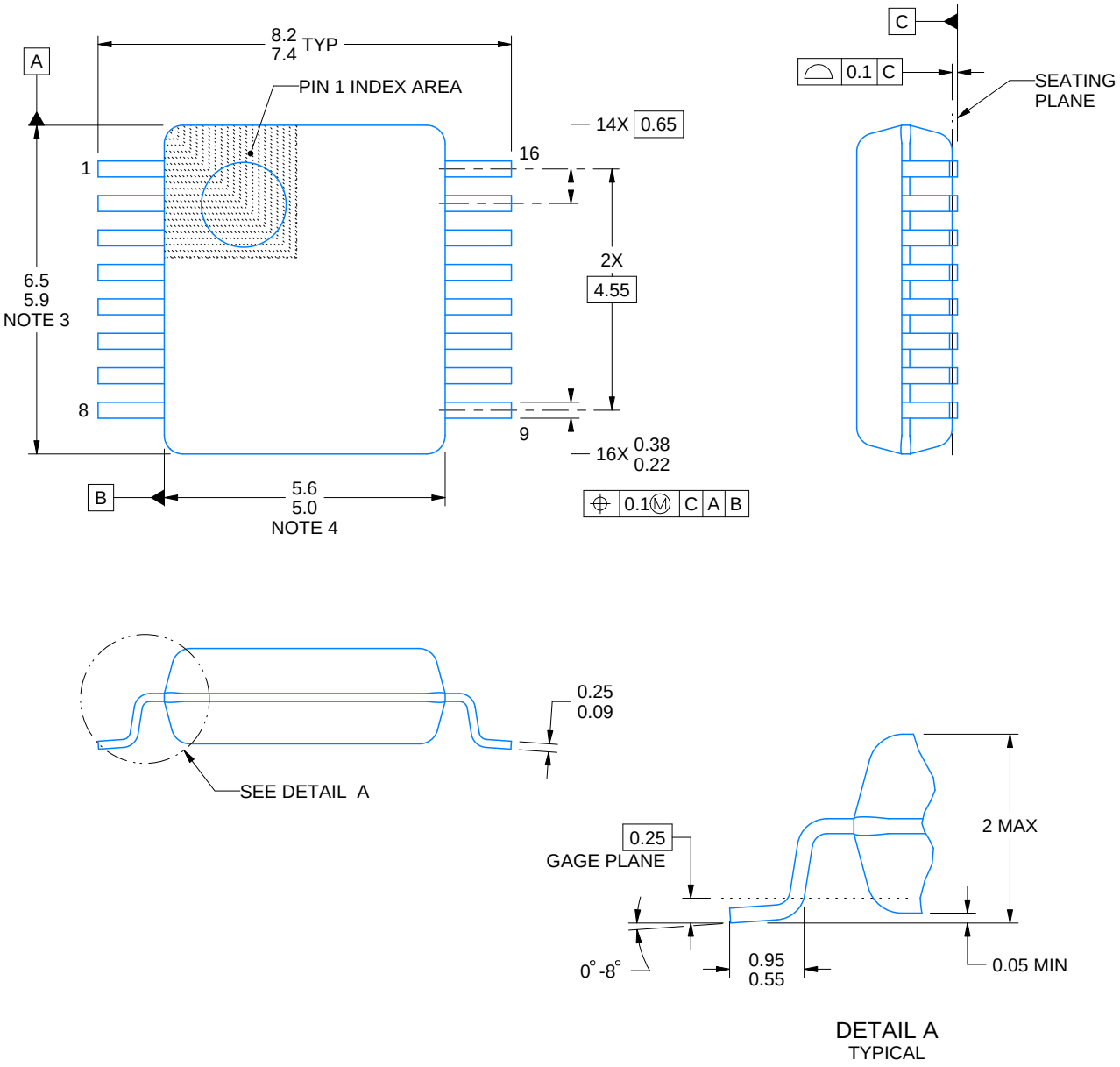
8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.

PACKAGE OUTLINE

DB0016A

SSOP - 2 mm max height

SMALL OUTLINE PACKAGE



NOTES:

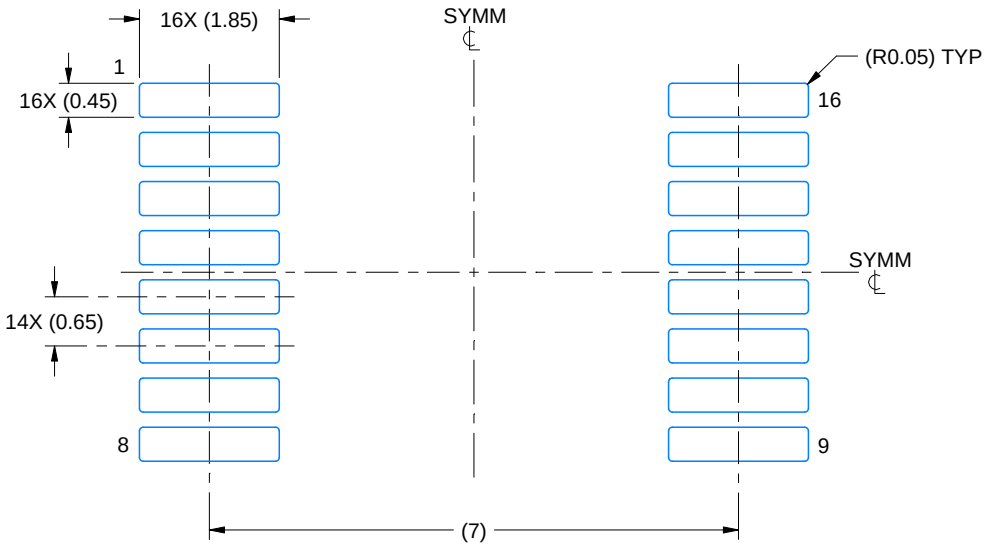
1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm per side.
4. Reference JEDEC registration MO-150.

EXAMPLE BOARD LAYOUT

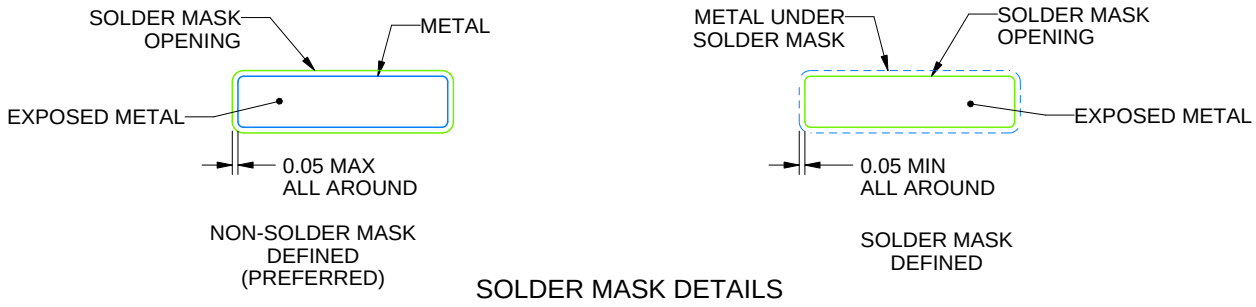
DB0016A

SSOP - 2 mm max height

SMALL OUTLINE PACKAGE



LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE: 10X



SOLDER MASK DETAILS

4220763/A 05/2022

NOTES: (continued)

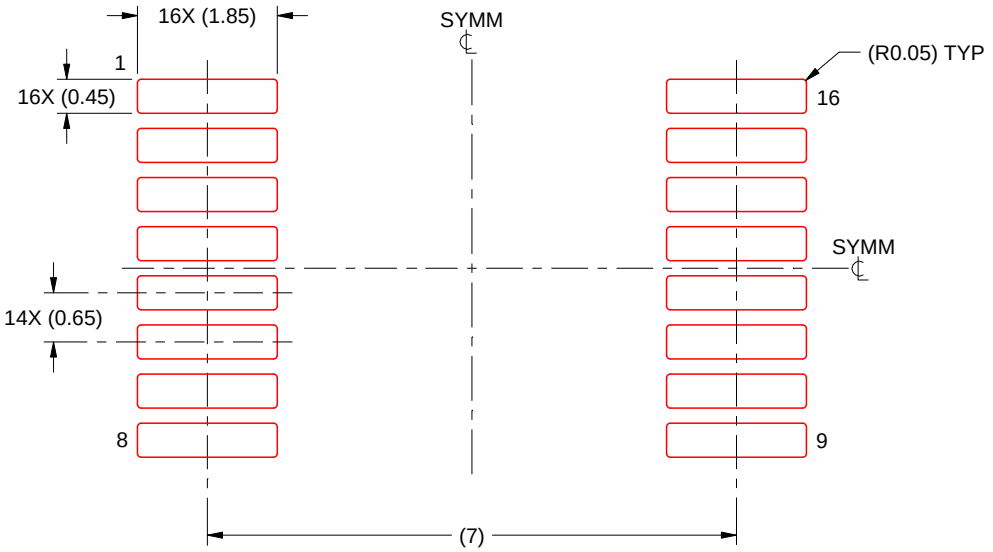
5. Publication IPC-7351 may have alternate designs.
6. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

EXAMPLE STENCIL DESIGN

DB0016A

SSOP - 2 mm max height

SMALL OUTLINE PACKAGE



SOLDER PASTE EXAMPLE
BASED ON 0.125 mm THICK STENCIL
SCALE: 10X

4220763/A 05/2022

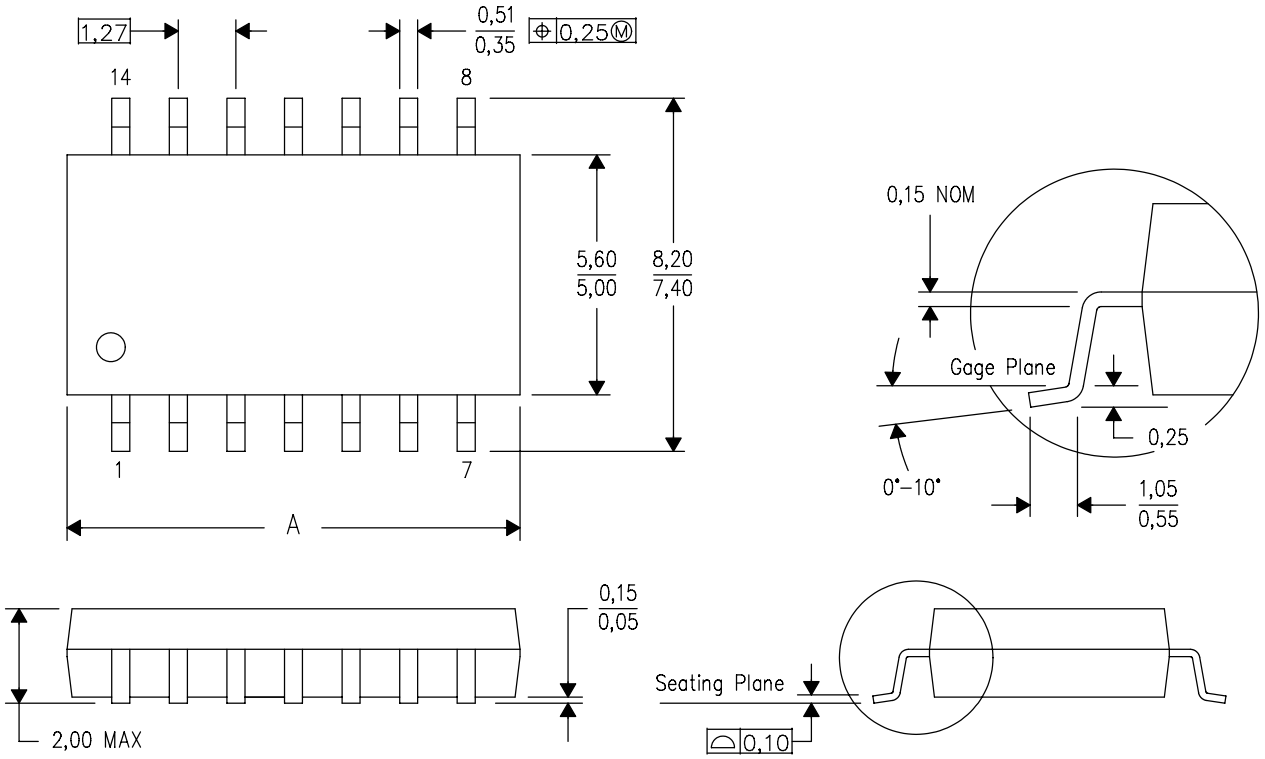
NOTES: (continued)

7. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
8. Board assembly site may have different recommendations for stencil design.

MECHANICAL DATA

NS (R-PDSO-G)** **PLASTIC SMALL-OUTLINE PACKAGE**

14-PINS SHOWN



DIM \ PINS **	14	16	20	24
A MAX	10,50	10,50	12,90	15,30
A MIN	9,90	9,90	12,30	14,70

4040062/C 03/03

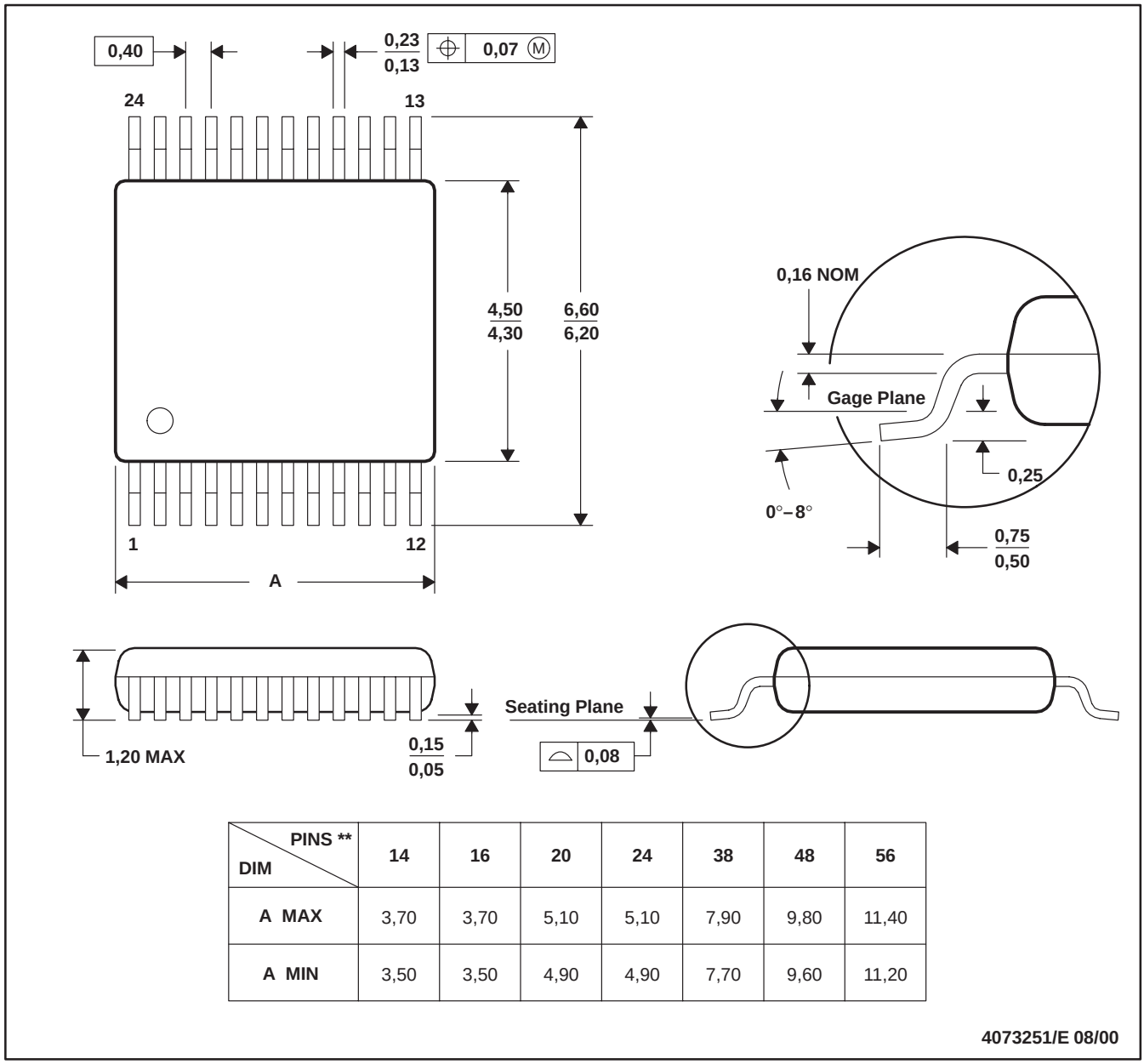
NOTES:
A. All linear dimensions are in millimeters.
B. This drawing is subject to change without notice.
C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15.

MECHANICAL DATA

MPDS006C – FEBRUARY 1996 – REVISED AUGUST 2000

DGV (R-PDSO-G)** **PLASTIC SMALL-OUTLINE**

24 PINS SHOWN



DIM \ PINS **	14	16	20	24	38	48	56
A MAX	3,70	3,70	5,10	5,10	7,90	9,80	11,40
A MIN	3,50	3,50	4,90	4,90	7,70	9,60	11,20

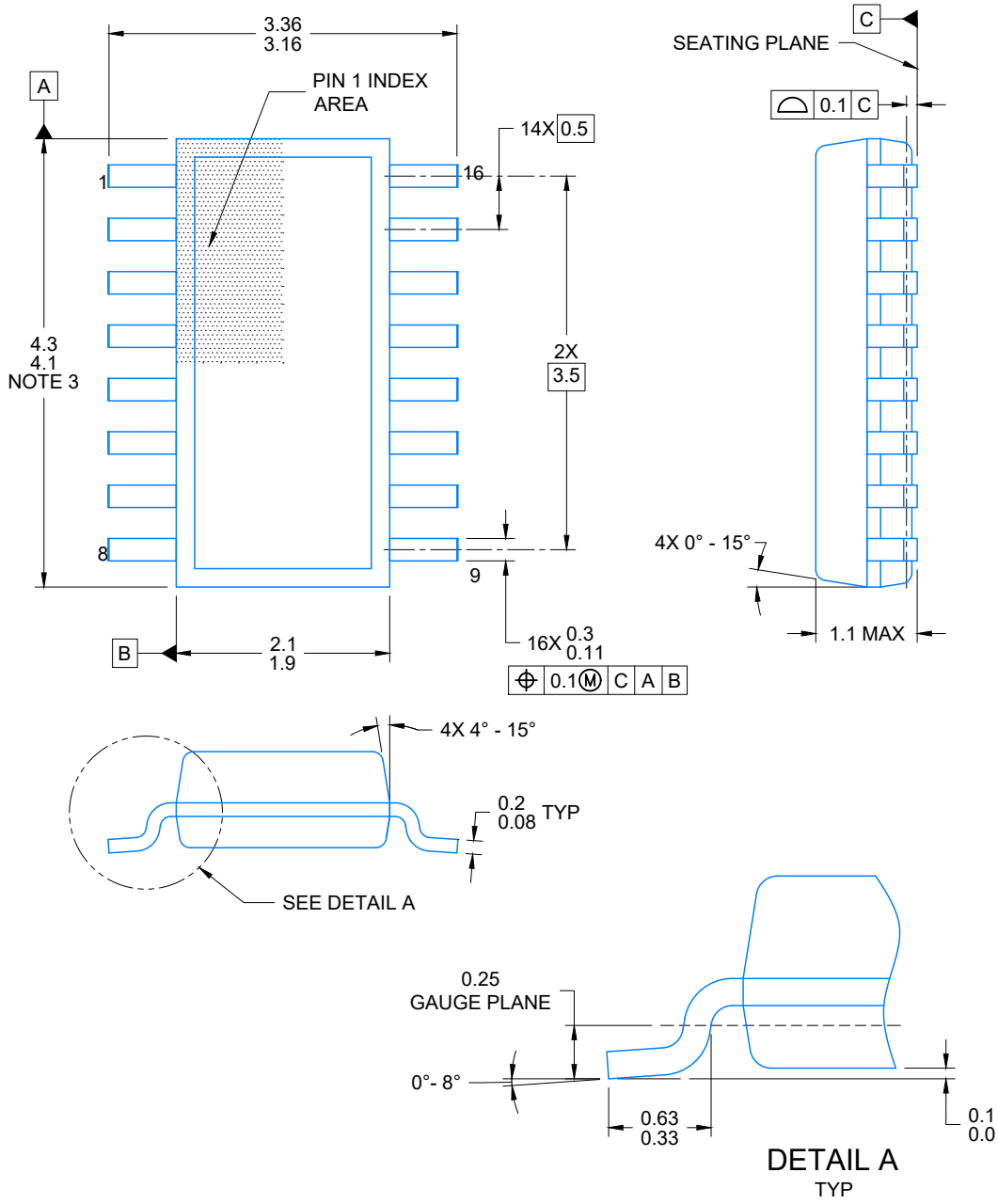
NOTES: A. All linear dimensions are in millimeters.
B. This drawing is subject to change without notice.
C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15 per side.
D. Falls within JEDEC: 24/48 Pins – MO-153
14/16/20/56 Pins – MO-194

PACKAGE OUTLINE

DYY0016A

SOT-23-THIN - 1.1 mm max height

PLASTIC SMALL OUTLINE



NOTES:

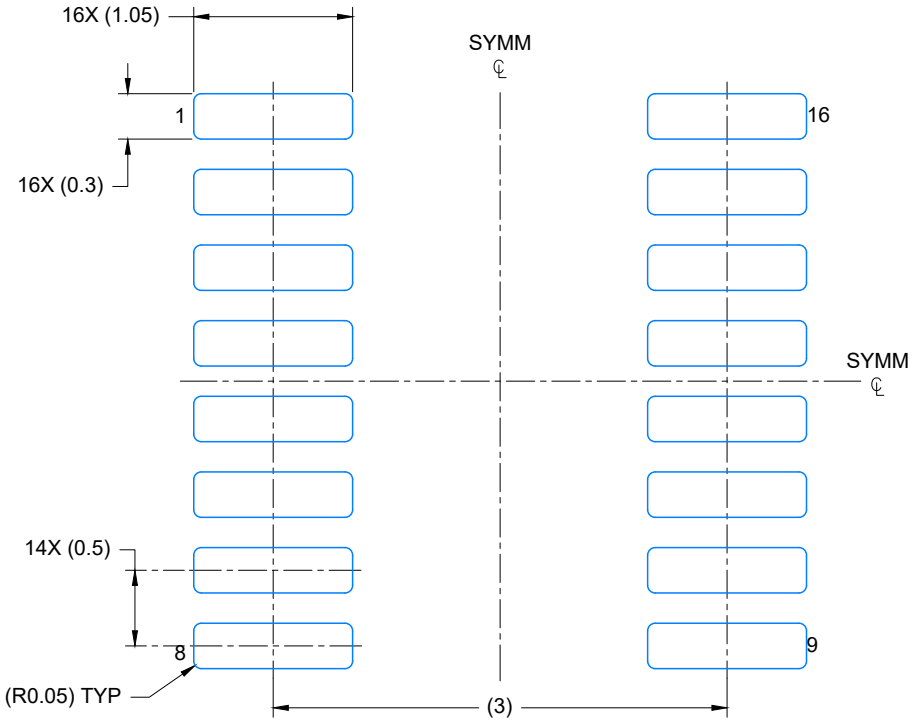
1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 per side.
4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.50 per side.
5. Reference JEDEC Registration MO-345, Variation AA

EXAMPLE BOARD LAYOUT

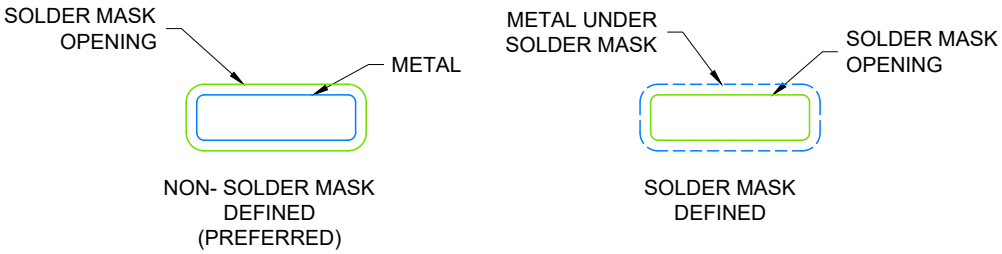
DYY0016A

SOT-23-THIN - 1.1 mm max height

PLASTIC SMALL OUTLINE



LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE: 20X



SOLDER MASK DETAILS

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NOTES: (continued)

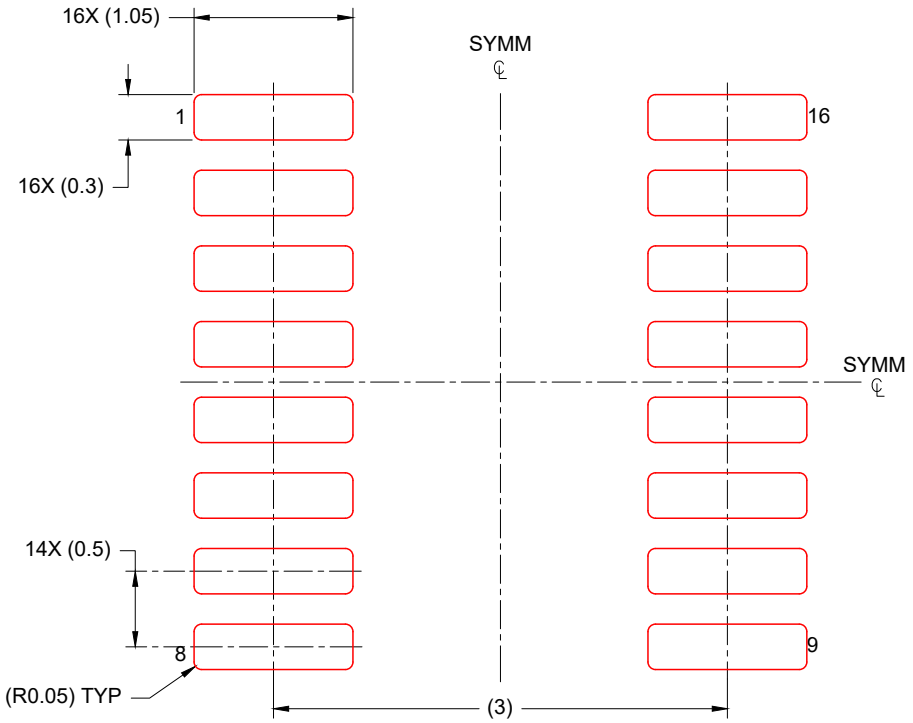
6. Publication IPC-7351 may have alternate designs.
7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

EXAMPLE STENCIL DESIGN

DYY0016A

SOT-23-THIN - 1.1 mm max height

PLASTIC SMALL OUTLINE



SOLDER PASTE EXAMPLE
BASED ON 0.125 mm THICK STENCIL
SCALE: 20X

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NOTES: (continued)

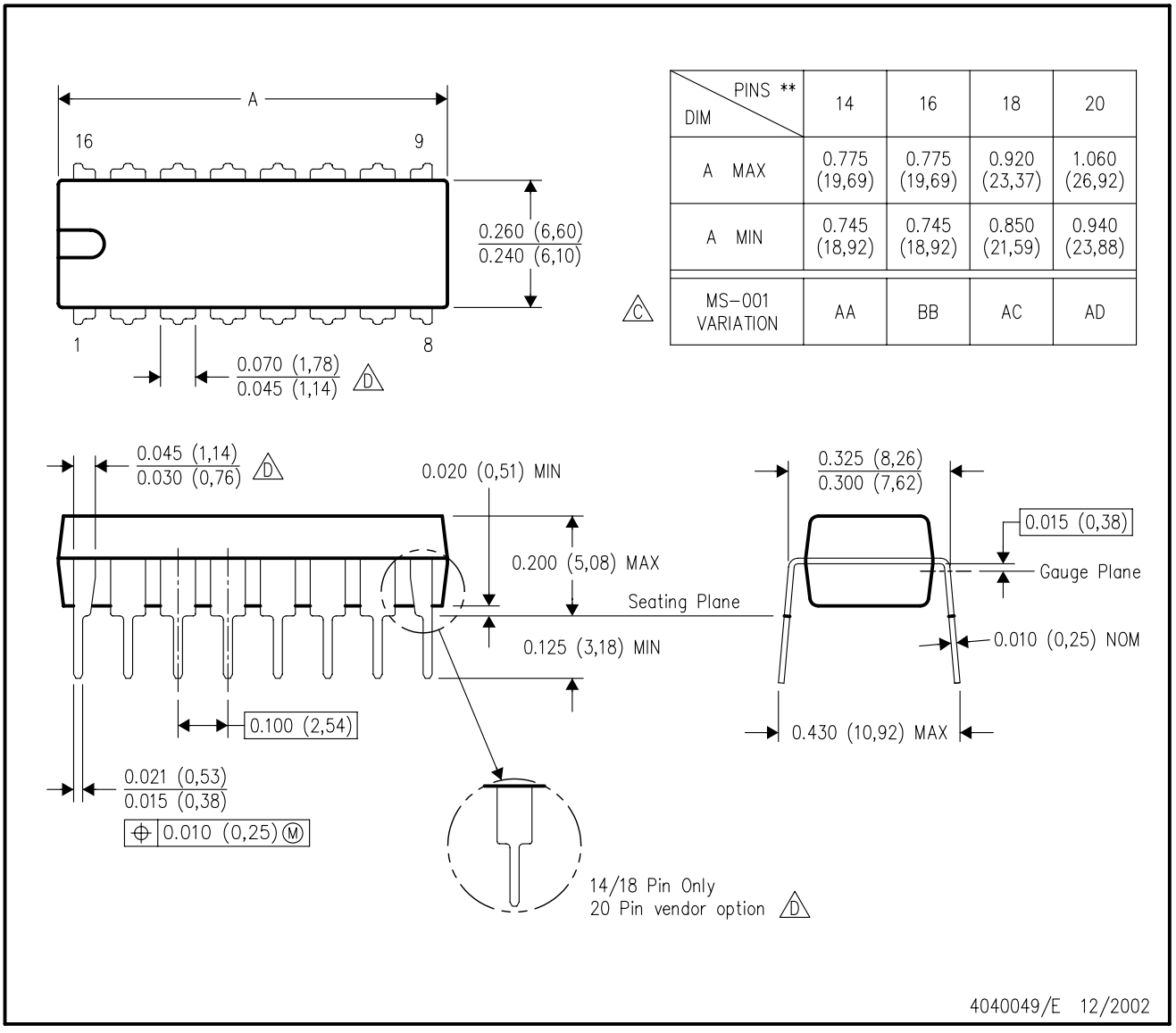
8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.

MECHANICAL DATA

N (R–PDIP–T**)

PLASTIC DUAL–IN–LINE PACKAGE

16 PINS SHOWN

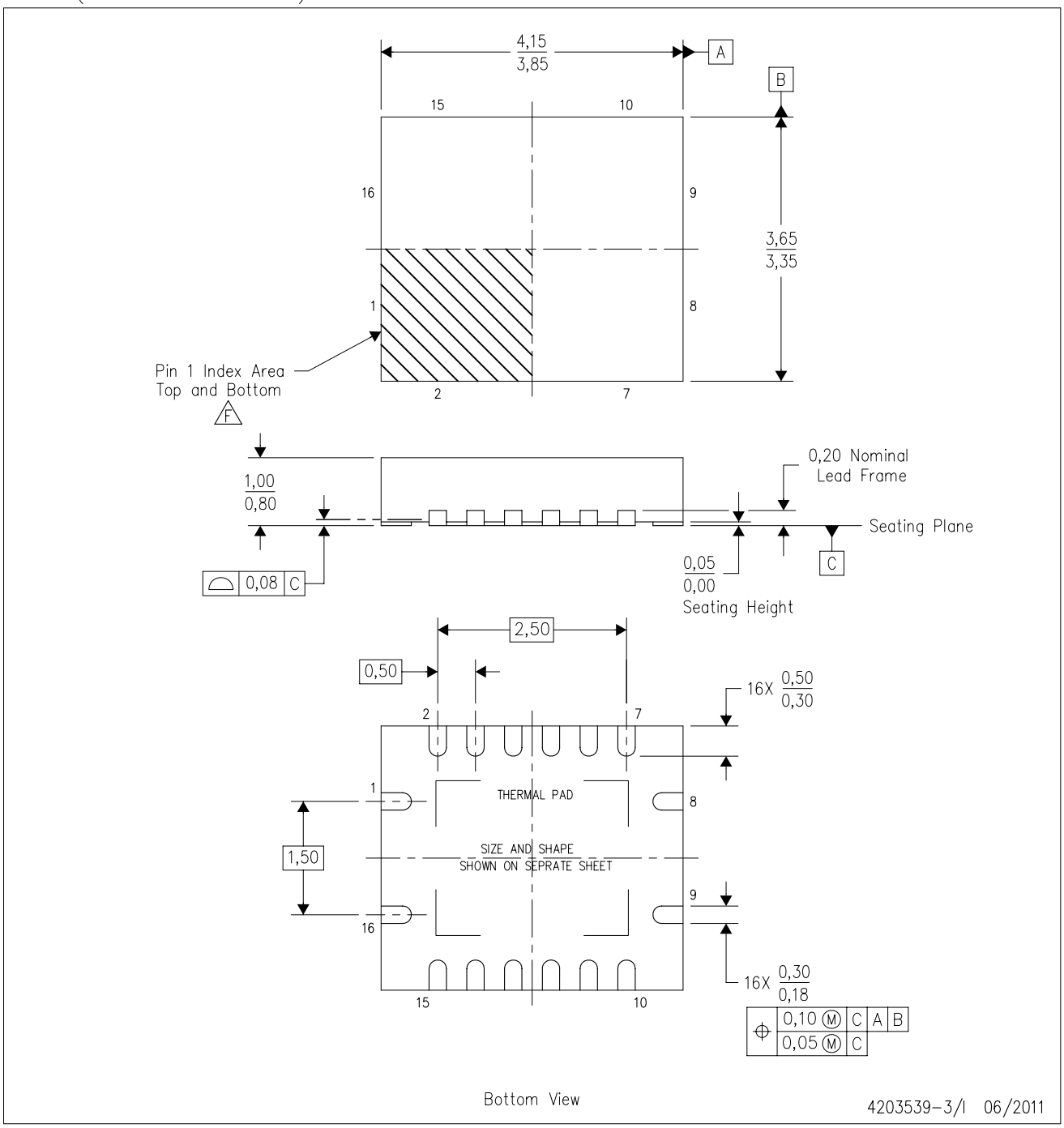


DIM \ PINS **	14	16	18	20
A MAX	0.775 (19,69)	0.775 (19,69)	0.920 (23,37)	1.060 (26,92)
A MIN	0.745 (18,92)	0.745 (18,92)	0.850 (21,59)	0.940 (23,88)
C MS–001 VARIATION	AA	BB	AC	AD

NOTES:
A. All linear dimensions are in inches (millimeters).
B. This drawing is subject to change without notice.
C. Falls within JEDEC MS–001, except 18 and 20 pin minimum body length (Dim A).
D. The 20 pin end lead shoulder width is a vendor option, either half or full width.

MECHANICAL DATA

RGY (R–PVQFN–N16) PLASTIC QUAD FLATPACK NO–LEAD



NOTES:
A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M–1994.
B. This drawing is subject to change without notice.
C. QFN (Quad Flatpack No–Lead) package configuration.
D. The package thermal pad must be soldered to the board for thermal and mechanical performance.
E. See the additional figure in the Product Data Sheet for details regarding the exposed thermal pad features and dimensions.
F. Pin 1 identifiers are located on both top and bottom of the package and within the zone indicated. The Pin 1 identifiers are either a molded, marked, or metal feature.
G. Package complies to JEDEC MO–241 variation BA.

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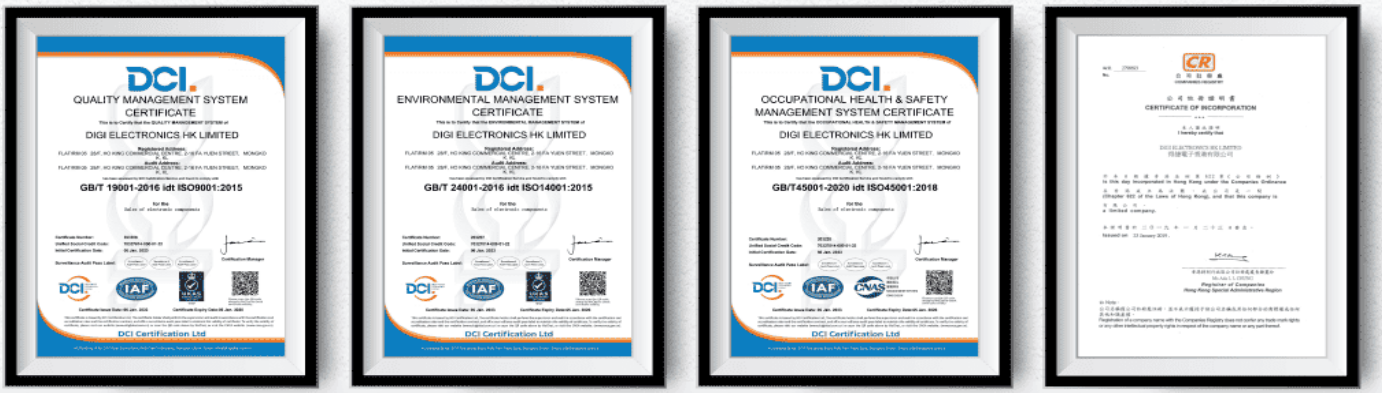

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